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## **QP50-6 TO**

## Description

Low dark current quadrant PIN photodiode with 4 x 12 mm<sup>2</sup> active area. Metal can type hermetic TO8S package with clear glass window.

#### **Features**

- 50 mm<sup>2</sup> Quadrant PIN detector
- High sensitivity
- Low dark current

## **Applications**

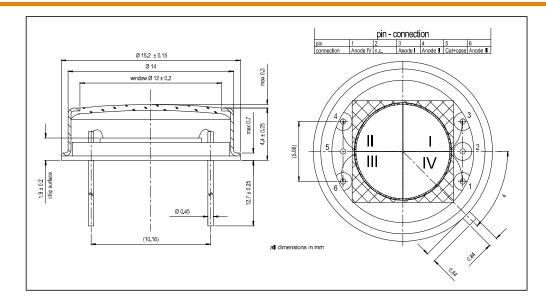
- Laser beam position sensor
- Autocollimators
- Optical tweezers
- Ellipsometers

#### **RoHS**

2011/65/EU

2015/863/EU

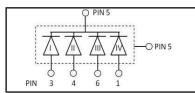
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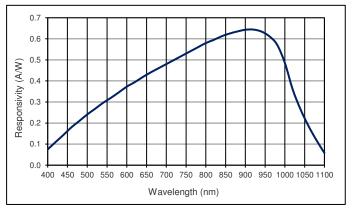
## Absolute maximum ratings

Symbol	Parameter	Min	Max	Unit
T <sub>STG</sub>	Storage temp	-55	125	°C
T <sub>OP</sub>	Operating temp	-40	100	°C
V <sub>max</sub>	Max reverse voltage		20	V
I <sub>PEAK</sub>	Peak DC current		10	mA

## Schematic



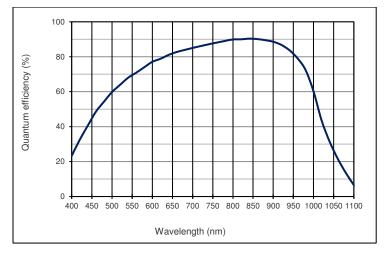
## Spectral response (23 °C)



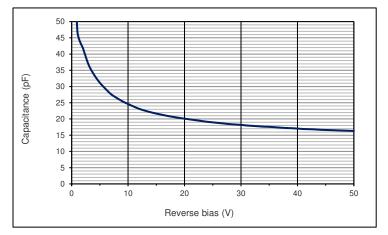
## Electro-optical characteristics @ 23 °C

Symbol	Characteristic	Test Condition	Min	Тур	Max	Unit
	Number of elements		4 quadrants			
	Active area	diameter 7980 (total)			(total)	μm
	Active area	per element		12		mm <sup>2</sup>
	Gap	between elements		42		μm
ID	Dark current	$V_R = 10 V$ ; per element		2.0	5.0	nA
С	Capacitance	V <sub>R</sub> = 0 V; per element		120		pF
		$V_R = 10 V$ ; per element		20		pF
	Responsivity	λ = 632 nm		0.4		A/W
		λ = 900 nm		0.64		A/W
tR	Rise time	$V_R$ = 0 V; $\lambda$ = 850 nm; $R_L$ = 50 $\Omega$		2000		ns
		$V_R$ = 10 V; $\lambda$ = 850 nm; $R_L$ = 50 $\Omega$		40		ns
	Shunt Resistance	$V_R = 5 \text{ mV}$ ; per element		50		MΩ
	N.E.P.	$V_R$ = 5 V; $\lambda$ = 900 nm; per element		4 E-14		W/√Hz
VBR	Breakdown voltage	$I_R = 2 \ \mu A$	20	50		V

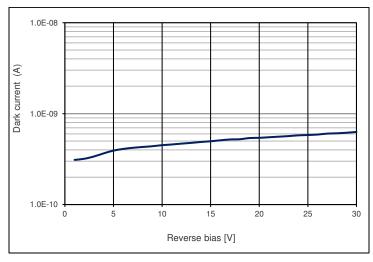
## Quantum efficiency (23 °C)



## Capacitance as fct of reverse bias (23 °C; per element)



## Dark current as fct of bias (23 °C; per element)



## **Optical inspection**

Optical inspection according to failure catalogue for optical sensors FK INS 201.

#### Package dimension:

Small quantities: Foam pad, boxed (12 cm x 16.5 cm)

#### Handling precautions:

- Soldering temperature max. 260 °C for 10 s. The device must be protected against solder flux vapor.
- Minimum pin length is 2 mm.
- For ESD protection standard precautionary measures are sufficient.
- For further questions please refer to document "Instructions for handling and processing".

Disclaimer: Due to our strive for continuous improvement, specifications are subject to change within our PCN policy according to JESD46C.

#### Ordering information (standard configurations)

Description	TE Part Number	MPQ
QP50-6 TO (TO8S)	3004334-F	1000 pcs

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